TOSHIBA Transistor Silicon PNP Epitaxial Type

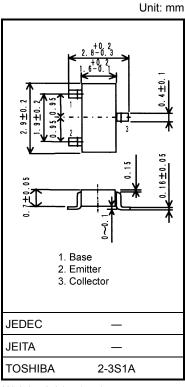
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High-Speed Switching Applications DC-DC Converter Applications Strobe Applications

- High DC current gain: $h_{FE} = 200 \text{ to } 500 \text{ (I}_{C} = -0.15 \text{ A)}$
- Low collector-emitter saturation voltage: $V_{CE (sat)} = -0.14 \text{ V (max)}$
- High-speed switching: $t_f = 37 \text{ ns (typ.)}$

Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V _{CBO}	-20	V	
Collector-emitter voltage		V _{CEO}	-20	V	
Emitter-base voltage		V _{EBO}	-7	V	
Collector current	DC	IC	-1.5	Α	
	Pulse	I _{CP}	-2.5		
Base current		IB	-150	mA	
Collector power dissipation	t = 10 s	PC	750	mW	
	DC	(Note 1)	500		
Junction temperature		Tj	150	°C	
Storage temperature range		T _{stg}	−55 to 150	°C	



Weight: 0.01 g (typ.)

Note 1: Mounted on an FR4 board (glass epoxy, 1.6 mm thick, Cu area: 645 mm²)

Note 2: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current		I _{CBO}	V _{CB} = -20 V, I _E = 0	_	_	-100	nA
Emitter cut-off current		I _{EBO}	V _{EB} = -7 V, I _C = 0	_	_	-100	nA
Collector-emitter breakdown voltage		V (BR) CEO	$I_C = -10 \text{ mA}, I_B = 0$	-20	_	_	٧
DC current gain		h _{FE} (1)	$V_{CE} = -2 \text{ V}, I_{C} = -0.15 \text{ A}$	200	_	500	
		h _{FE} (2)	$V_{CE} = -2 \text{ V}, I_{C} = -0.5 \text{ A}$	125	_	_	
Collector-emitter saturation voltage		V _{CE (sat)}	$I_C = -0.5 \text{ A}, I_B = -17 \text{ mA}$	_	_	-0.14	٧
Base-emitter saturation voltage		V _{BE (sat)}	$I_C = -0.5 \text{ A}, I_B = -17 \text{ mA}$	_	_	-1.10	V
Switching time	Rise time	t _r	See Figure 1.	_	40	_	
	Storage time	t _{stg}	$V_{CC} \approx -10 \text{ V}, R_L = 20 \Omega$	_	135	_	ns
	Fall time	t _f	-I _{B1} = I _{B2} = −17 mA	_	37	_	

Marking

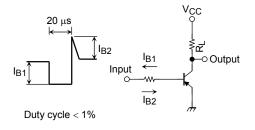
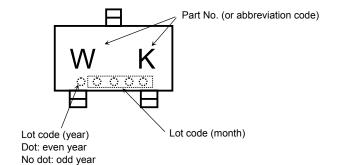
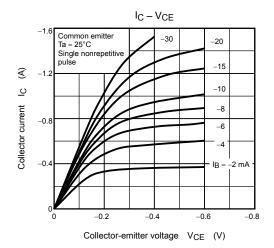
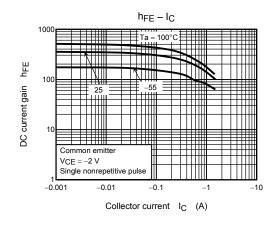


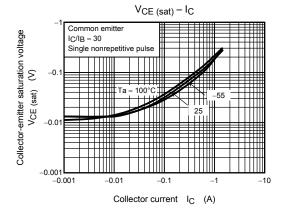
Figure 1 Switching Time Test Circuit & Timing Chart

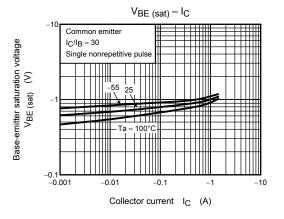


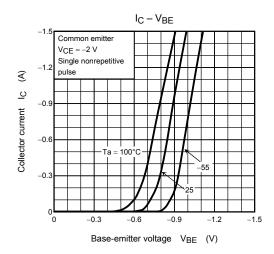
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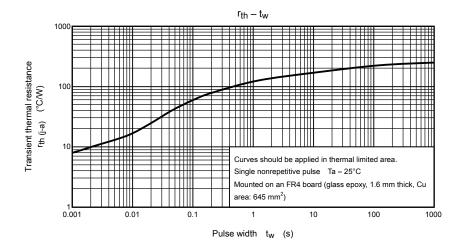


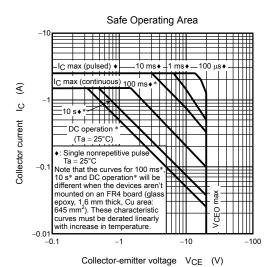






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